



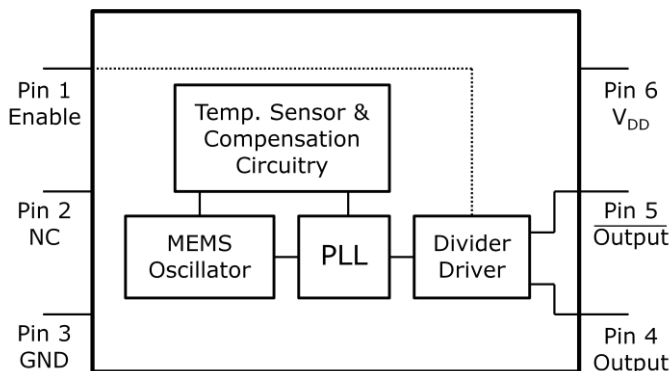
Low-Jitter Precision LVDS Oscillator

General Description

The DSC1103 & DSC1123 series of high performance oscillators utilizes a proven silicon MEMS technology to provide excellent jitter and stability over a wide range of supply voltages and temperatures. By eliminating the need for quartz or SAW technology, MEMS oscillators significantly enhance reliability and accelerate product development, while meeting stringent clock performance criteria for a variety of communications, storage, and networking applications.

DSC1103 has a standby feature allowing it to completely power-down when EN pin is pulled low; whereas for DSC1123, only the outputs are disabled when EN is low. Both oscillators are available in industry standard packages, including the small 3.2x2.5 mm², and are "drop-in" replacements for standard 6-pin LVDS quartz crystal oscillators.

Block Diagram



Output Enable Modes

EN Pin	DSC1103	DSC1123
High	Outputs Active	Outputs Active
NC	Outputs Active	Outputs Active
Low	Standby	Outputs Disabled

Features

- **Low RMS Phase Jitter: <1 ps (typ)**
- **High Stability: ± 10 , ± 25 , ± 50 ppm**
- **Wide Temperature Range**
 - Industrial: -40° to 85° C
 - Ext. commercial: -20° to 70° C
- **High Supply Noise Rejection: -50 dBc**
- **Short Lead Time: 2 Weeks**
- **Wide Freq. Range: 10 to 460 MHz**
- **Small Industry Standard Footprints**
 - 3.2x2.5, 5.0x3.2, and 7.0x5.0 mm
- **Excellent Shock & Vibration Immunity**
 - Qualified to MIL-STD-883
- **High Reliability**
 - 20x better MTF than quartz oscillators
- **Low Current Consumption**
- **Supply Range of 2.25 to 3.6 V**
- **Standby & Output Enable Function**
- **Lead Free & RoHS Compliant**
- **LVPECL & HCSL Versions Available**

Applications

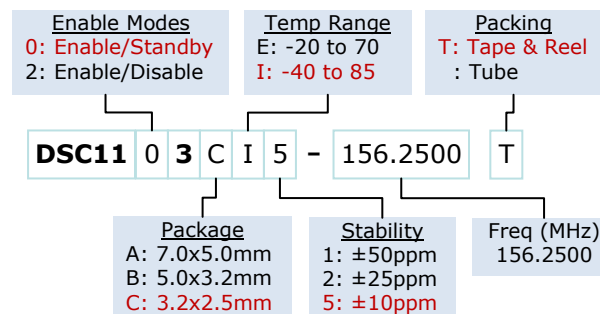
- **Storage Area Networks**
 - SATA, SAS, Fibre Channel
- **Passive Optical Networks**
 - EPON, 10G-EPON, GPON, 10G-PON
- **Ethernet**
 - 1G, 10GBASE-T/KR/LR/SR, and FCoE
- **HD/SD/SDI Video & Surveillance**
- **PCI Express: Gen 1 & Gen 2**
- **DisplayPort**

Absolute Maximum Ratings

Item	Min	Max	Unit	Condition
Supply Voltage	-0.3	+4.0	V	
Input Voltage	-0.3	$V_{DD}+0.3$	V	
Junction Temp	-	+150	°C	
Storage Temp	-55	+150	°C	
Soldering Temp	-	+260	°C	40sec max.
ESD	-		V	
HBM		4000		
MM		400		
CDM		1500		

Note: 1000+ years of data retention on internal memory

Ordering Code



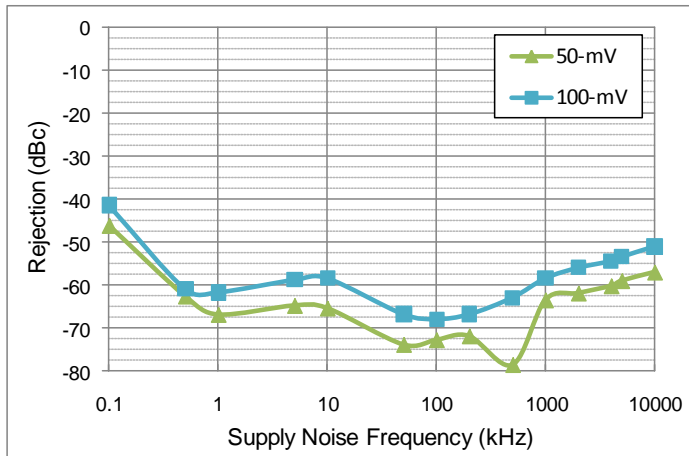
Specifications

Parameter		Condition	Min.	Typ.	Max.	Unit
Supply Voltage ¹	V_{DD}		2.25		3.6	V
Supply Current	I_{DD}	EN pin low – outputs are disabled DSC1103 DSC1123		20	0.095 22	mA
Frequency Stability	Δf	Includes frequency variations due to initial tolerance, temp. and power supply voltage			±10 ±25 ±50	ppm
Aging	Δf	1 year @25°C			±5	ppm
Startup Time ²	t_{SU}	T=25°C			5	ms
Input Logic Levels						
Input logic high	V_{IH}		0.75x V_{DD}		-	V
Input logic low	V_{IL}		-		0.25x V_{DD}	
Output Disable Time ³	t_{DA}				5	ns
Output Enable Time	t_{EN}	DSC1103 DSC1123			5 20	ms ns
Enable Pull-Up Resistor ⁴		Pull-up resistor exist		40		kΩ
LVDS Outputs						
Supply Current	I_{DD}	Output Enabled, $R_L=50\Omega$		29	32	mA
Output offset Voltage	V_{OS}	R=100Ω Differential	1.125		1.4	V
Delta Offset Voltage	ΔV_{OS}				50	mV
Pk to Pk Output Swing	V_{PP}	Single-Ended		350		mV
Output Transition time ³						
Rise Time	t_R	20% to 80% $R_L=50\Omega$, $C_L=2pF$		200		ps
Fall Time	t_F					
Frequency	f_0	Single Frequency	10		460	MHz
Output Duty Cycle	SYM	Differential	48		52	%
Period Jitter	J_{PER}			2.5		ps _{RMS}
Integrated Phase Noise	J_{PH}	200kHz to 20MHz @156.25MHz 100kHz to 20MHz @156.25MHz 12kHz to 20MHz @156.25MHz		0.28 0.4 1.7	2	ps _{RMS}

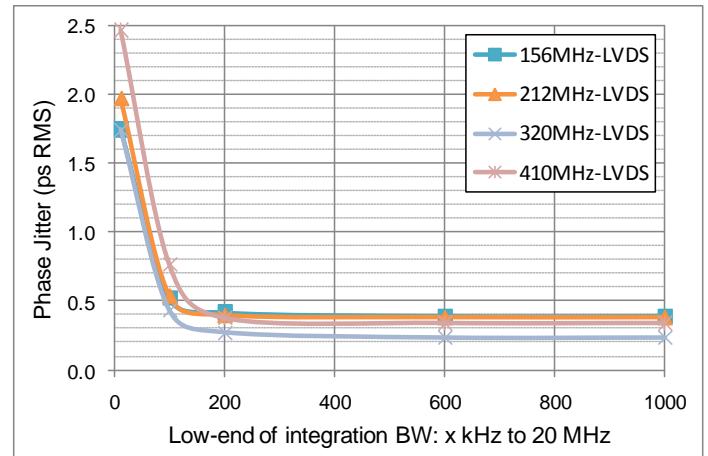
Notes:

- Pin 6 V_{DD} should be filtered with 0.1uF capacitor.
- t_{SU} is time to 100ppm of output frequency after V_{DD} is applied and outputs are enabled.
- Output Waveform and Test Circuit figures below define the parameters.
- Output is enabled if pad is floated or not connected.

Nominal Performance Parameters (Unless specified otherwise: $T=25^{\circ}\text{C}$, $V_{DD}=3.3\text{V}$)

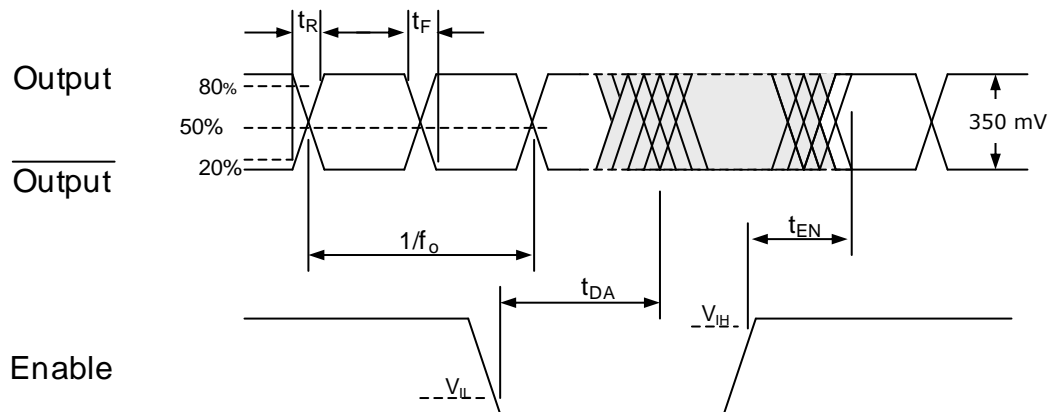


Power supply rejection ratio

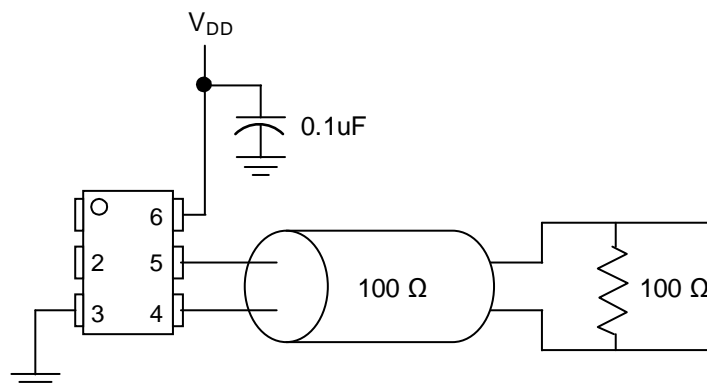


Phase jitter (integrated phase noise)

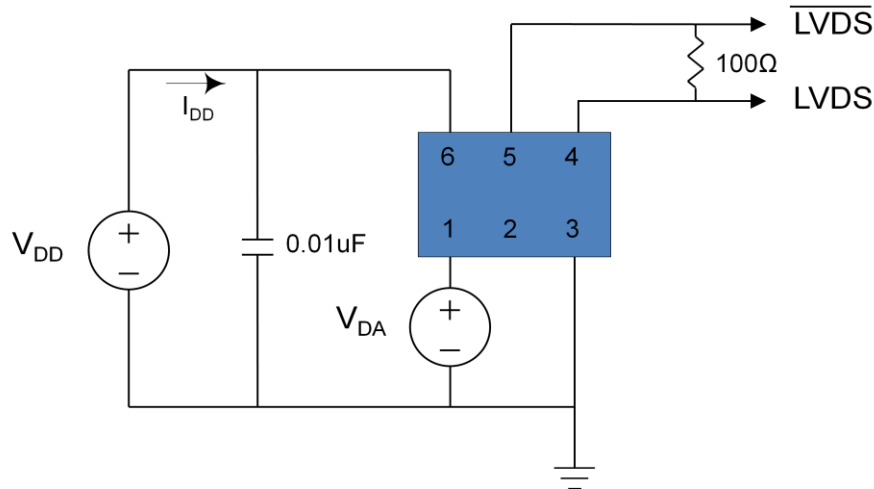
Output Waveform



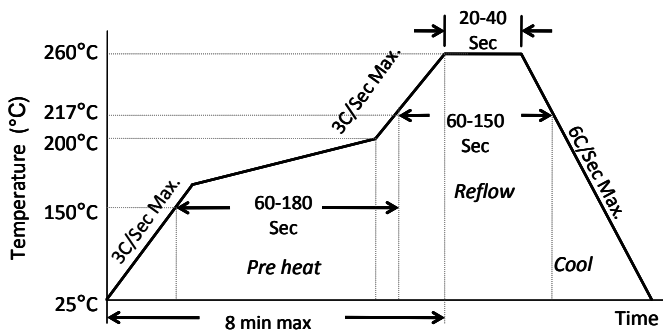
Typical Termination Scheme



Test Circuit



Solder Reflow Profile

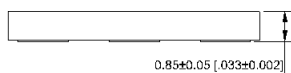
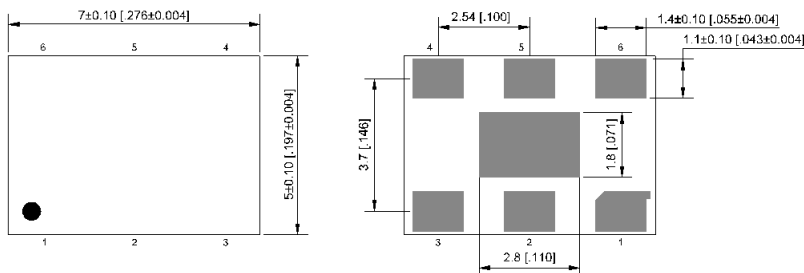


MSL 1 @ 260°C refer to JSTD-020C	
Ramp-Up Rate (200°C to Peak Temp)	3°C/Sec Max.
Preheat Time 150°C to 200°C	60-180 Sec
Time maintained above 217°C	60-150 Sec
Peak Temperature	255-260°C
Time within 5°C of actual Peak	20-40 Sec
Ramp-Down Rate	6°C/Sec Max.
Time 25°C to Peak Temperature	8 min Max.

Package Dimensions

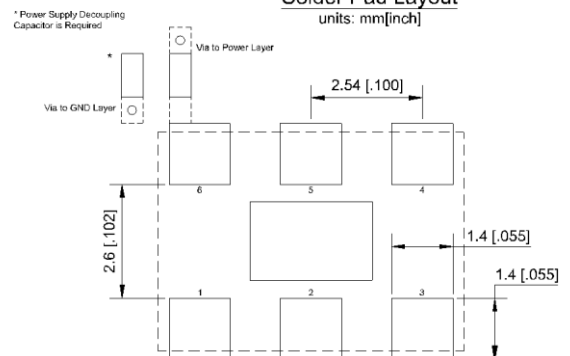
7.0 x 5.0 mm Plastic Package

External Dimensions
units: mm[inch]



No.	Pin terminal
1	Enable
2	nc
3	GND
4	Output
5	Output
6	VDD

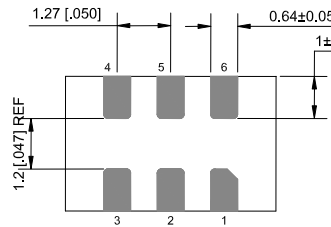
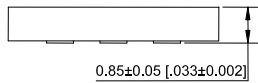
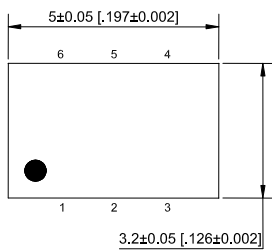
Recommended
Solder Pad Layout
units: mm[inch]



5.0 x 3.2 mm Plastic Package

External Dimensions

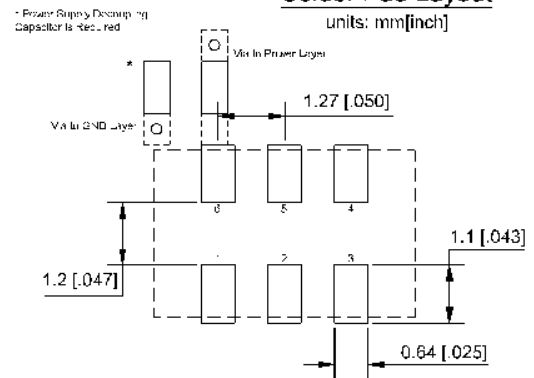
units: mm[inch]



No.	Pin terminal
1	Enable
2	nc
3	GND
4	Output
5	Output
6	VDD

Recommended Solder Pad Layout

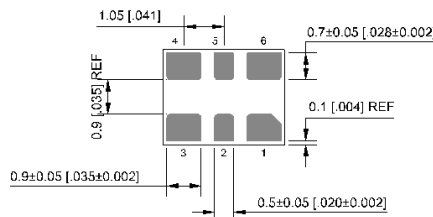
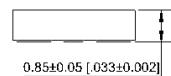
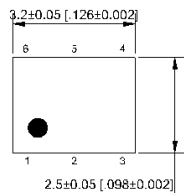
units: mm[inch]



3.2 x 2.5 mm Plastic Package

External Dimensions

units: mm[inch]



No.	Pin terminal
1	Enable
2	nc
3	GND
4	Output
5	Output
6	VDD

Recommended Solder Pad Layout

units: mm[inch]

